



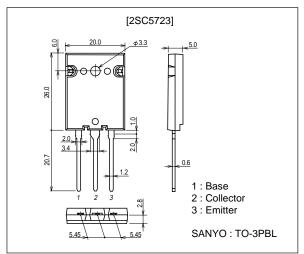
Ultrahigh-Definition CRT Display Horizontal Deflection Output Applications

Features

- · High speed.
- High breakdown voltage(V_{CBO}=1500V).
- · High reliability(Adoption of HVP process).
- · Adoption of MBIT process.

Package Dimensions

unit : mm 2048B



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1500	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		25	Α
Collector Current (Pulse)	ICP		50	Α
Collector Dissipation	Po		3.5	W
	PC	Tc=25°C	180	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	01111
Collector Cutoff Current	ІСВО	V _{CB} =800V, I _E =0			10	μΑ
Collector Cutoff Current	ICES	V _{CE} =1500V, R _{BE} =0			1.0	mA
Collector Sustain Voltage	VCEO(sus)	IC=100mA, IB=0	800			V
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			1.0	mA

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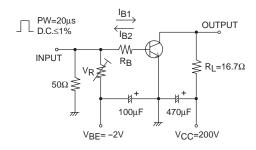
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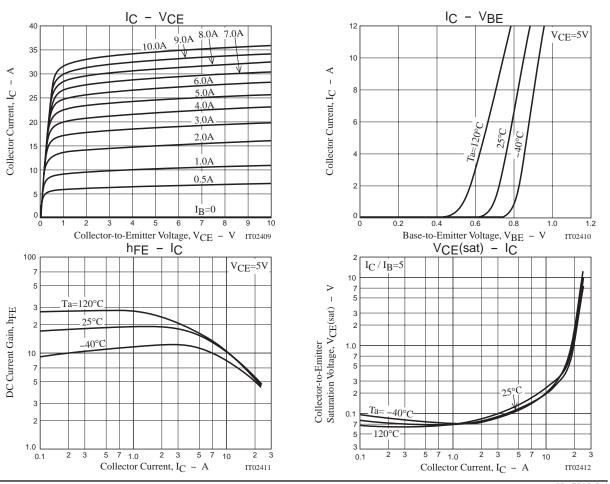
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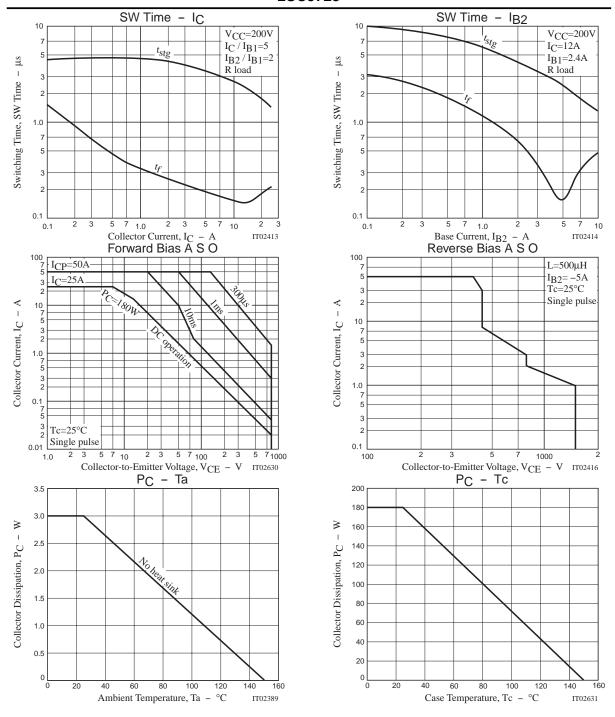
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
DC Current Gain	hFE(1)	VCE=5V, IC=1A	15			
	hFE(2)	V _{CE} =5V, I _C =20A	4		7	
Collectoe-to-Emitter Saturation Voltage	VCE(sat)	IC=18A, IB=4.5A			3	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =18A, I _B =4.5A			1.5	V
Storage Time	tstg	IC=12A, IB1=2.4A, IB2=-4.8A			3.0	μs
Fall Time	t _f	I _C =12A, I _{B1} =2.4A, I _{B2} =-4.8A			0.2	μs

Switching Time Test Circuit







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